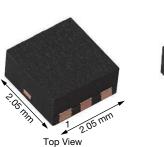
## SQA470EJ

www.vishay.com

**Vishay Siliconix** 

## Automotive N-Channel 30 V (D-S) 175 °C MOSFET





Marking Code: QCXXXX

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	30			
$R_{DS(on)}$ ( $\Omega$ ) at $V_{GS}$ = 4.5 V	0.065			
$R_{DS(on)}$ ( $\Omega$ ) at $V_{GS}$ = 2.5 V	0.095			
I <sub>D</sub> (A)	2.25			
Configuration	Single			
Package	PowerPAK SC-70			

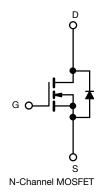
PowerPAK<sup>®</sup> SC-70-6L Single

#### **FEATURES**

- TrenchFET<sup>®</sup> power MOSFET
- AEC-Q101 qualified <sup>d</sup>
- 100 %  $R_q$  and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ROHS COMPLIANT HALOGEN FREE



ABSOLUTE MAXIMUM RATINGS (T <sub>C</sub> = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V <sub>DS</sub>	30	V	
Gate-source voltage		V <sub>GS</sub>	± 12		
Continuous drain current <sup>a</sup>	T <sub>C</sub> = 25 °C	I.	2.25		
	T <sub>C</sub> = 125 °C	- I <sub>D</sub>	2.25		
Continuous source current (diode conduction) <sup>a</sup>		I <sub>S</sub>	2.25	А	
Pulsed drain current <sup>a</sup>		I <sub>DM</sub>	9		
Single pulse avalanche current	L = 0.1 mH	I <sub>AS</sub>	9		
Single pulse avalanche energy		E <sub>AS</sub>	4	mJ	
Maximum power dissipation <sup>b</sup>	T <sub>C</sub> = 25 °C	PD	13.6	w	
	T <sub>C</sub> = 125 °C	۳D	4.5		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C	
Soldering recommendations (peak temperature) <sup>e, f</sup>			260	C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount <sup>c</sup>	R <sub>thJA</sub>	90	°C/W	
Junction-to-case (drain)		R <sub>thJC</sub>	11	0/10	

Notes

- a. Package limited
- b. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)
- d. Parametric verification ongoing
- e. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

S17-0424-Rev. A, 03-Apr-17 S17-0424-Rev. A, 03-Apr-17 For technical questions, contact: <u>automos.techsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u> www.vishay.com

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<i>\ /</i> <sup>1</sup>	0.1		
Viehav	<u>S</u> 11	Incor	NIV
Vishay			11 ^

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static		·						
Drain-source breakdown voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_D = 250 \mu A$		30	-	-	V	
Gate-source threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$		0.6	1.1		
Gate-source leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 8 V$		-	-	± 100	nA	
Zero gate voltage drain current		$V_{GS} = 0 V$	V <sub>DS</sub> = 30 V	-	-	1		
	I <sub>DSS</sub>	$V_{GS} = 0 V$	$V_{DS} = 30 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	50	μA	
		$V_{GS} = 0 V$	$V_{DS} = 30 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	250		
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	$V_{GS} = 4.5 V$	$V_{DS} \ge 5 V$	10	-	-	Α	
Drain-source on-state resistance <sup>a</sup>		$V_{GS} = 4.5 V$	I <sub>D</sub> = 3 A	-	0.038	0.065	Ω	
		$V_{GS} = 4.5 V$	I <sub>D</sub> = 3 A, T <sub>J</sub> = 125 °C	-	-	0.077		
	R <sub>DS(on)</sub>	V <sub>GS</sub> = 4.5 V	I <sub>D</sub> = 3 A, T <sub>J</sub> = 175 °C	-	-	0.090		
		V <sub>GS</sub> = 2.5 V	I <sub>D</sub> = 3 A	-	0.048	0.095		
Forward transconductance b	<b>g</b> fs	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 2 A		-	16	-	S	
Dynamic <sup>b</sup>	•	•			•	•		
Input capacitance	C <sub>iss</sub>			-	312	440		
Output capacitance	C <sub>oss</sub>	$V_{GS} = 0 V \qquad V_{DS} = 20 V, f = 1 MHz$	-	56	80	pF		
Reverse transfer capacitance	C <sub>rss</sub>			-	29		41	
Total gate charge <sup>c</sup>	Qg		$V_{GS} = 4.5 \text{ V}$ $V_{DS} = 15 \text{ V}, I_D = 4.2 \text{ A}$	-	4.6	6	nC	
Gate-source charge <sup>c</sup>	Q <sub>gs</sub>	V <sub>GS</sub> = 4.5 V		-	0.65	-		
Gate-drain charge <sup>c</sup>	Q <sub>gd</sub>			-	0.9	-		
Gate resistance	R <sub>g</sub>	f = 1 MHz		2.1	3.6	5.7	Ω	
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>			-	7.3	11		
Rise time <sup>c</sup>	t <sub>r</sub>	$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = 10 \; V,  R_{\text{L}} = 10 \; \Omega \\ I_{\text{D}} \cong 1 \; A,  V_{\text{GEN}} = 4.5 \; V,  R_{\text{g}} = 1 \; \Omega \end{array}$		-	18	26	ns	
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>			-	21	32		
Fall time <sup>c</sup>	t <sub>f</sub>			-	9.5	14		
Source-Drain Diode Ratings and Char	acteristics <sup>b</sup>							
Pulsed current <sup>a</sup>	I <sub>SM</sub>			-	-	24	Α	
Forward voltage	V <sub>SD</sub>	I <sub>F</sub> = 4.5 A, V <sub>GS</sub> = 0 V			0.75	1.2	V	

Notes

a. Pulse test; pulse width  $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%$ 

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

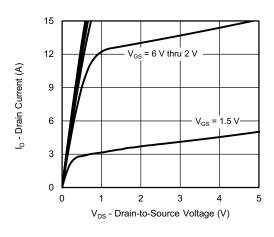
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2

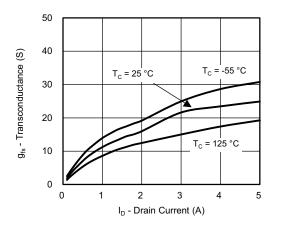


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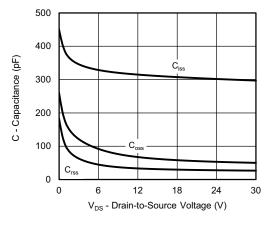
### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



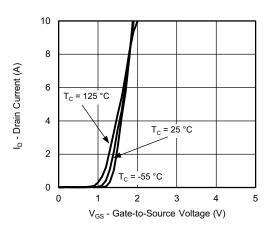
**Output Characteristics** 



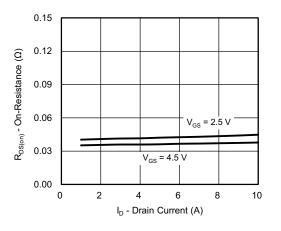
Transconductance



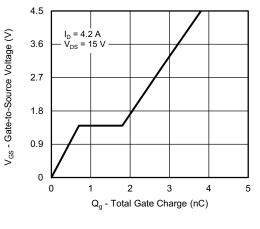
Capacitance



**Transfer Characteristics** 



**On-Resistance vs. Drain Current** 



Gate Charge

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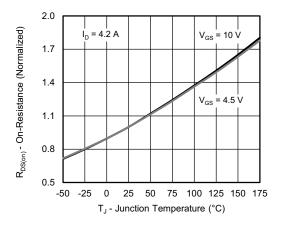
Document Number: 75522

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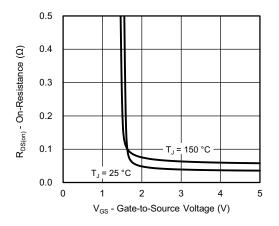


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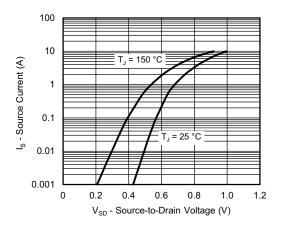
### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



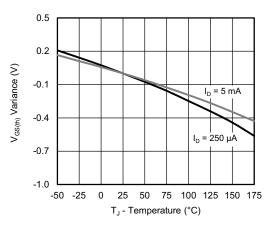
**On-Resistance vs. Junction Temperature** 



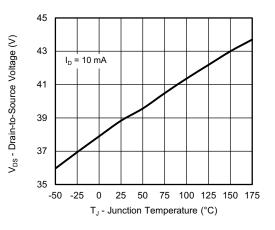
On-Resistance vs. Gate-to-Source Voltage



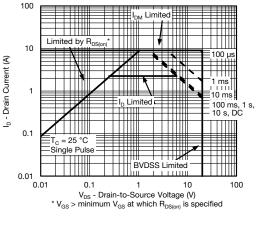
Source Drain Diode Forward Voltage



Threshold Voltage



Drain Source Breakdown vs. Junction Temperature



Safe Operating Area

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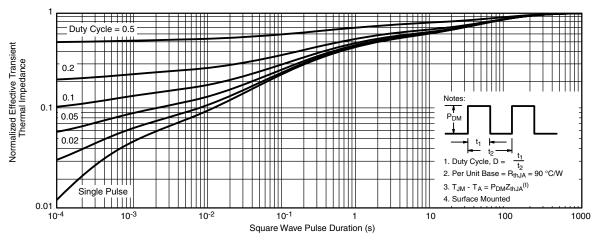
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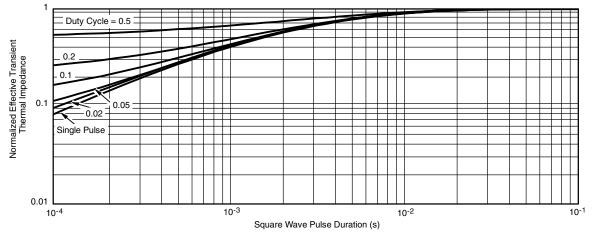


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#### **THERMAL RATINGS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



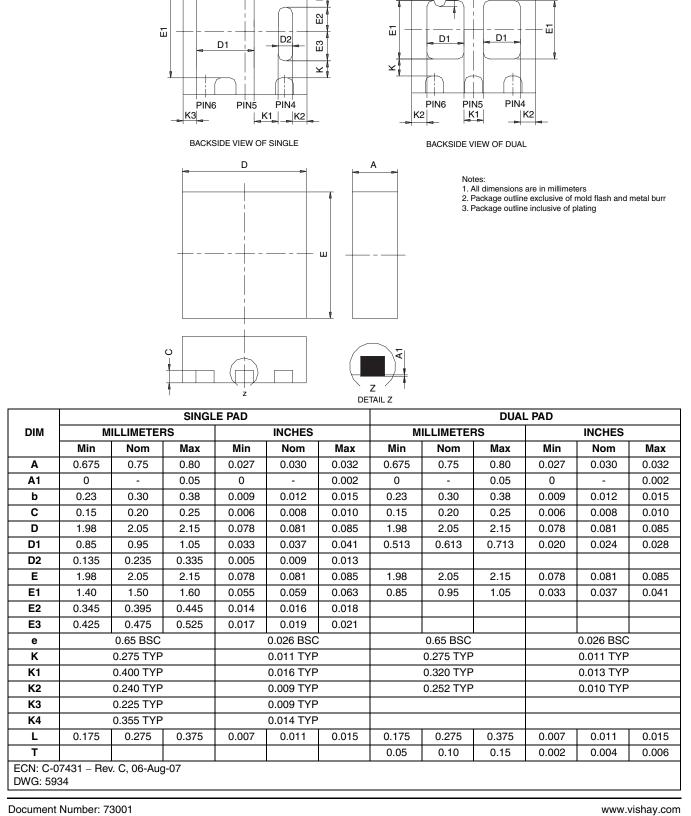
Normalized Thermal Transient Impedance, Junction-to-Case

#### Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?75522">www.vishay.com/ppg?75522</a>.



## PowerPAK<sup>®</sup> SC70-6L

# b PIN2 PIN1 PIN3 \_ ₹

## Package Information Vishay Siliconix

\_ ₿

b

PIN3

PIN2

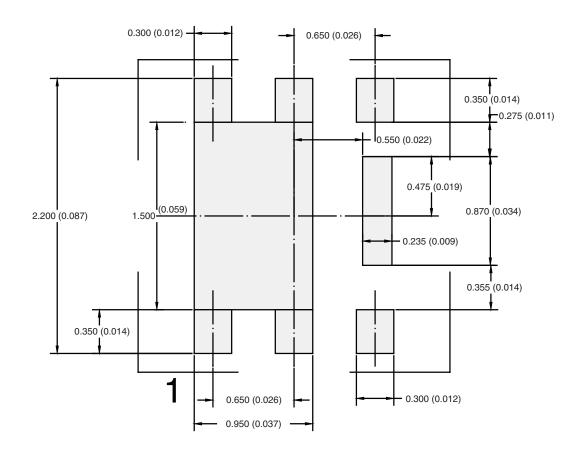
PIN1

¥

# VISHA



## RECOMMENDED PAD LAYOUT FOR PowerPAK<sup>®</sup> SC70-6L Single



Dimensions in mm/(Inches)

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